

International IOR Rectifier

1N3879(R), 1N3889(R) 6/ 12/ 16FL(R) SERIES

FAST RECOVERY DIODES

Stud Version

Major Ratings and Characteristics

Parameters	1N3879- 1N3883	1N3889- 1N3893	6FL	12FL	16FL	Units
I _{F(AV)} @ T _C = 100°C	6 *	12 *	6	12	16	A
I _{F(RMS)}	9.5	19	9.5	19	25	A
I _{FSM} @ 50Hz	72	145	110	145	180	A
@ 60Hz	75 *	150 *	115	150	190	A
I ² t @ 50Hz	26	103	60	103	160	A ² s
@ 60Hz	23	94	55	94	150	A ² s
I ² √t	363	856	1452	1452	2290	I ² √s
V _{RRM} range	50 to 400 *		50 to 1000			V
t _{rr} range	see table					ns
T _J range	- 65 to 150					°C

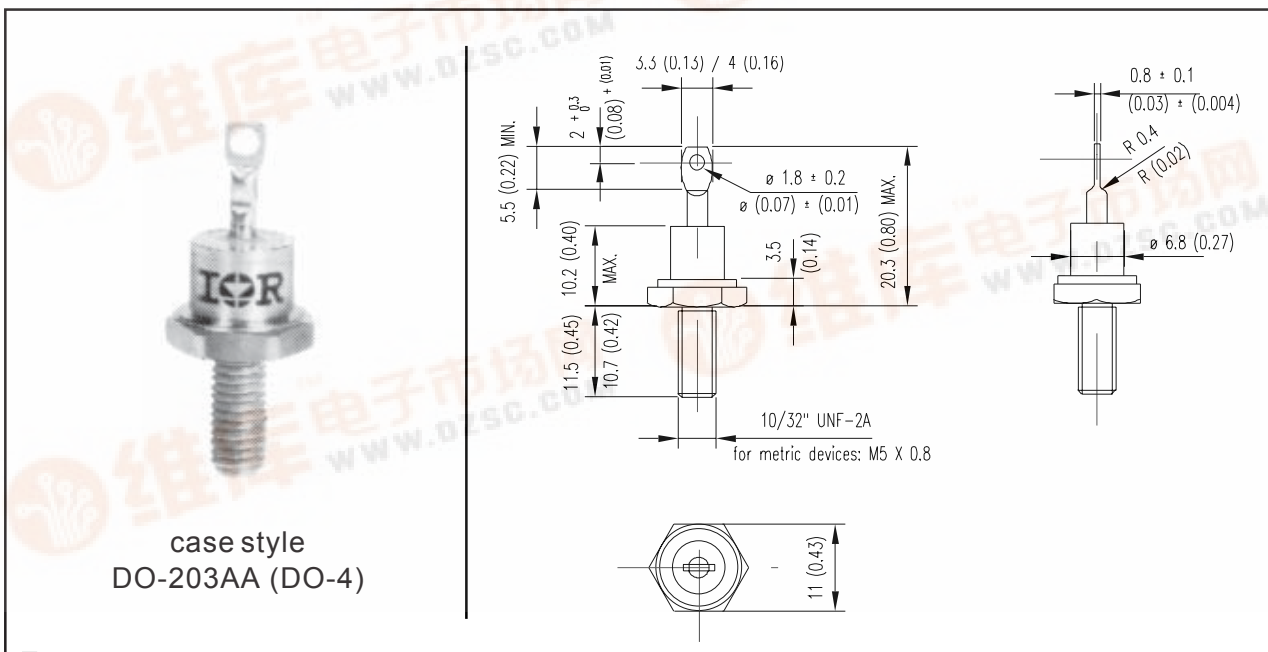
* JEDEC registered values.

Description

This range of fast recovery diodes is designed for applications in DC power supplies, inverters, converters, choppers, ultrasonic systems and for use as a free wheeling diode.

Features

- Short reverse recovery time
- Low stored charge
- Wide current range
- Excellent surge capabilities
- Standard JEDEC types
- Stud cathode and stud anode versions
- Fully characterised reverse recovery conditions



1N3879(R), 1N3889(R), 6/ 12/ 16FL(R) Series

ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{RRM} max. repetitive peak and off-state voltage V	V_{RSM} , maximum non-repetitive peak voltage V	I_{RRM} max. $T_J = 25^\circ\text{C}$ μA	I_{RRM} max. $T_J = 100^\circ\text{C}$ mA	I_{RRM} max. $T_J = 150^\circ\text{C}$ mA
1N3879.	-	50	75	15 *	1.0 *	3.0 *
1N3880.		100	150			
1N3881.		200	250			
1N3882.		300	350			
1N3883.		400	450			
1N3889.	-	50	75	25 *	3.0 *	5.0 *
1N3890.	-	100	150			
1N3891.	-	200	250			
1N3892.	-	300	350			
1N3893.	-	400	450			
6FL.. 12FL.. 16FL..	5	50	75	50	-	6.0
	10	100	150			
	20	200	275			
	40	400	500			
	60	600	725			
	80	800	950			
	100	1000	1250			

Forward Conduction

Parameter	1N3879. 1N3883.	6FL..	1N3889. 1N3893. 12FL..	16FL..	Units	Conditions
$I_{F(AV)}$ Max. average forward current @ $T_C = 100^\circ\text{C}$	6*	6	12 *	16	A	180° conduction, half sine wave. DC
$I_{F(RMS)}$ Max. RMS current	9.5	9.5	19	25	A	
I_{FSM} Max. peak, one-cycle non-repetitive forward current	85	130	170	215	A	t = 10ms No voltage t = 8.3ms reapplied t = 10ms 100% V_{RRM} t = 8.3ms reapplied Sinusoidal half wave
	90	135	180	225		
	72	110	145	180		
	75 *	115	150 *	190		
I^2t Maximum I^2t for fusing	36	86	145	230	A^2s	t = 10ms No voltage t = 8.3ms reapplied t = 10ms 100% V_{RRM} t = 8.3ms reapplied Initial $T_J = 150^\circ\text{C}$
	33	78	130	210		
	26	60	103	160		
	23	55	94	150		
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	363	856	1452	2290	$A^2\sqrt{s}$	t = 0.1 to 10ms, no voltage reapplied
V_{FM} Max. forward voltage	1.4 *	1.4	1.4 *	1.4	V	$T_J = 25^\circ\text{C}$, $I_F = \text{rated } I_{F(AV)}$ (D.C.)
	1.5 *	1.5	1.5 *	1.5		$T_C = 100^\circ\text{C}$, $I_{FM} = \pi \times \text{rated } I_{F(AV)}$

* JEDEC registered value

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Recovery Characteristics

Parameter	1N3879. 1N3883.	1N3889. 1N3893.	6FL.. 12FL.. 16FL.. S02 S05	Units	Conditions
t_{rr} Max. reverse recovery time	150	150		ns	$T_J = 25^\circ\text{C}, I_F = 1\text{A to } V_R = 30\text{V}, dI_F/dt = 100\text{A}/\mu\text{s}$
	300 *	300 *	200 500		$T_J = 25^\circ\text{C}, dI_F/dt = 25\text{A}/\mu\text{s}, I_{FM} = p \times \text{rated } I_{F(AV)}$
$I_{RM(REC)}$ Max. peak recovery current	4 *	5 *	...	---	$I_{FM} = p \times \text{rated } I_{F(AV)}$
Q_{RR} Max. reverse recovered charge	400	350		nC	$T_J = 25^\circ\text{C}, I_F = 1\text{A to } V_R = 30\text{V}, dI_F/dt = 100\text{A}/\mu\text{s}$
	400	400			$T_J = 25^\circ\text{C}, dI_F/dt = 25\text{A}/\mu\text{s}, I_{FM} = p \times \text{rated } I_{F(AV)}$

* JEDEC registered value

Thermal and Mechanical Specification

Parameter		1N3879. 1N3883. 6FL..	1N3889. 1N3893. 12FL..	16FL..	Units	Conditions
T _J	Max. junction operating temperature range	-65 to 150			°C	
T _{stg}	Max. storage temperature range					
R _{thJC}	Max. thermal resistance, junction to case	2.5	2.0	1.6	C/W	DC operation
R _{thCS}	Max. thermal resistance, case to heatsink	0.5				Mounting surface, smooth, flat and greased
T	Allowable mounting torque	1.5 ^{+0-10%}			Nm	Not lubricated threads
		13			lbf.in	
		1.2 ^{+0-10%}			Nm	Lubricated threads
		10			lbf.in	
wt	Approximate weight	7 (0.25)			g (oz)	
Case style		DO-203AA(DO-4)			JEDEC	

ΔR_{thJC} Conduction

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

	1N3879. 1N3883. 6FL..	1N3889. 1N3893. 12FL..	16FL..	1N3879. 1N3883. 6FL..	1N3889. 1N3893. 12FL..	16FL..		
Conduction angle	Sinusoidal conduction			Rectangular conduction			Units	Conditions
180°	0.58	0.46	0.37	0.33	0.26	0.21	K/W	$T_J = 150^\circ\text{C}$
120°	0.60	0.48	0.39	0.58	0.46	0.37		
60°	1.28	1.02	0.82	1.28	1.02	0.82		
30°	2.20	1.76	1.41	2.20	1.76	1.41		

1N3879(R), 1N3889(R), 6/ 12/ 16FL(R) Series

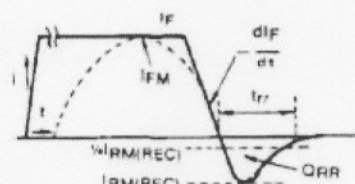
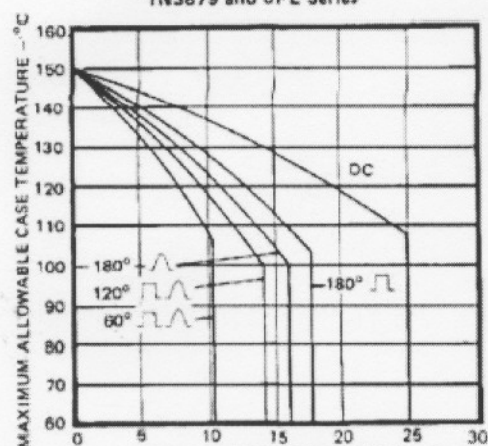
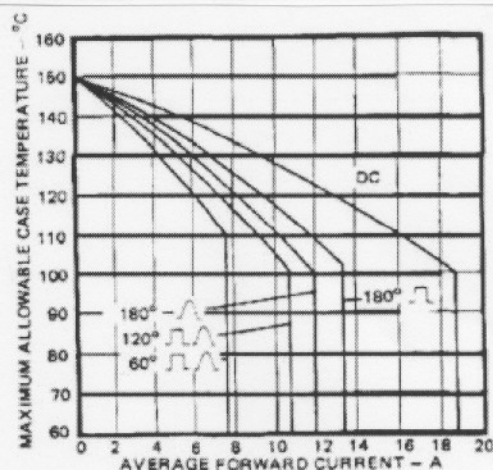
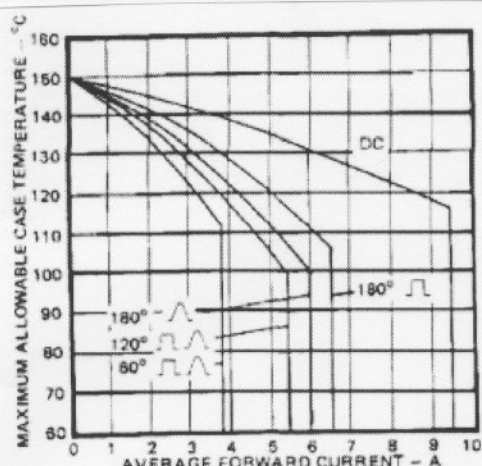
Ordering Information Table

Device Code							
A	16	F	L	R	60	M	S02
①	②	③	④	⑤	⑥	⑦	⑧

1	- Omit = Standard or Fast Recovery Diode A = Avalanche Diode
2	- Current Code $I_{(AVG)}$ = Exact Current Rating
3	- F = Diode
4	- Omit = Standard Recovery Diode L = Only for Fast Diode
5	- Omit = Stud Forward Polarity R = Stud Reverse Polarity
6	- Voltage code: Code x 10 = V_{RRM} (see Voltage Ratings table)
7	- Outlines: Omit = Stud Base UNF Thread M = Stud Base Metric Thread
8	- t_{rr} code only for Fast Diode (see Recovery Characteristics table)

Outline Table

	Conforms to JEDEC DO-203AA (DO-4) All dimensions in millimeters



- I_F, I_{FM} = Peak forward current prior to commutation
- $-di_F/dt$ = Rate of fall of forward current
- I_{RMIREC} = Peak reverse recovery current
- t_{rr} = Reverse recovery time
- Q_{RR} = Reverse recovered charge

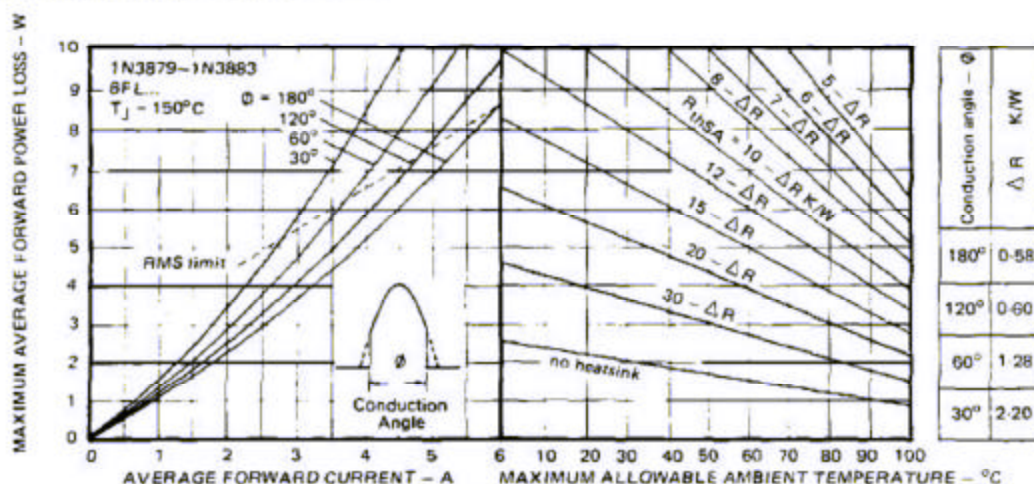


Fig. 5 - Current Rating Nomogram (Sinusoidal Waveforms), 1N3879 and 6FL Series

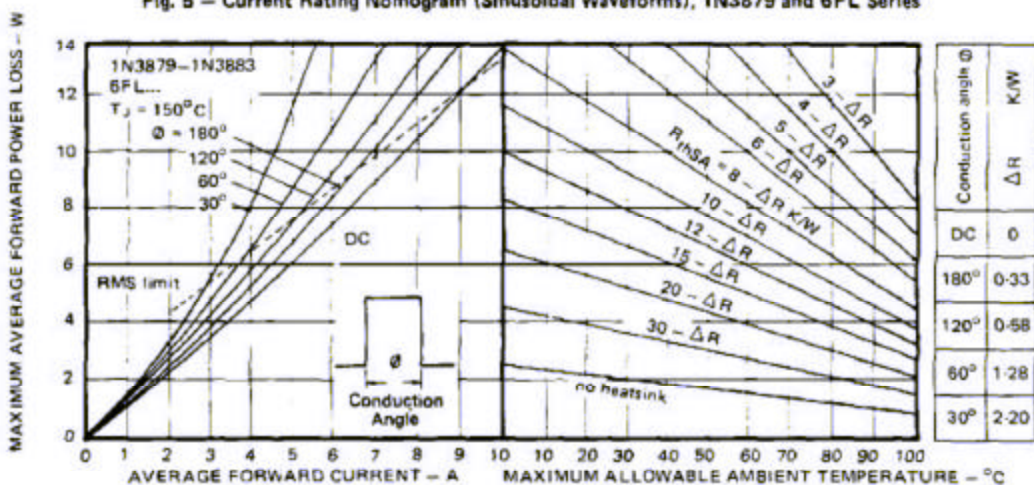


Fig. 6 - Current Rating Nomogram (Rectangular Waveforms), 1N3879 and 6FL Series

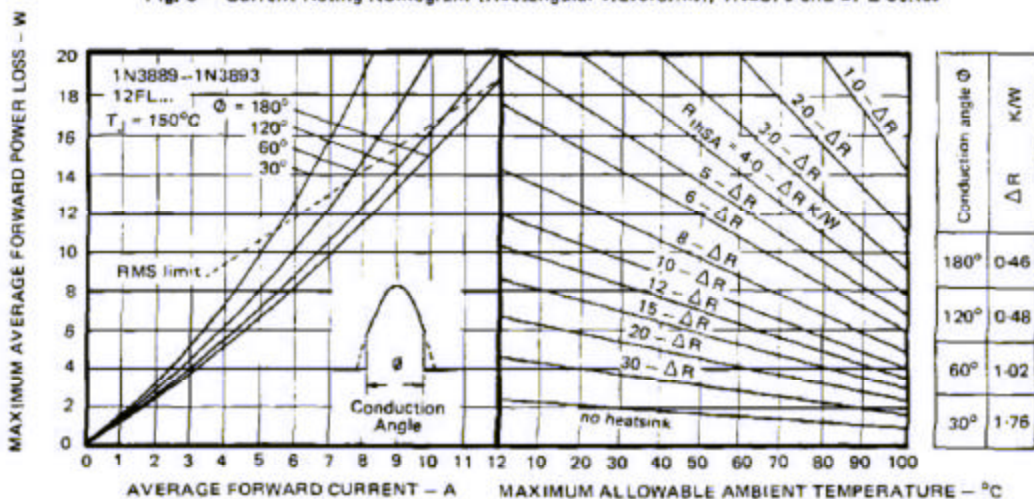


Fig. 7 - Current Rating Nomogram (Sinusoidal Waveforms), 1N3889 and 12FL Series

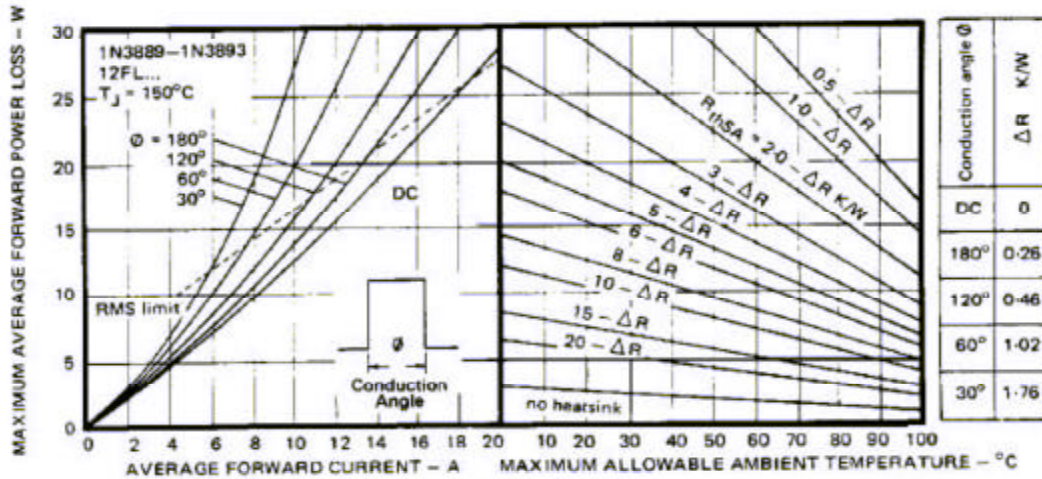


Fig. 8 - Current Rating Nomogram (Rectangular Waveforms), 1N3889 and 12FL Series

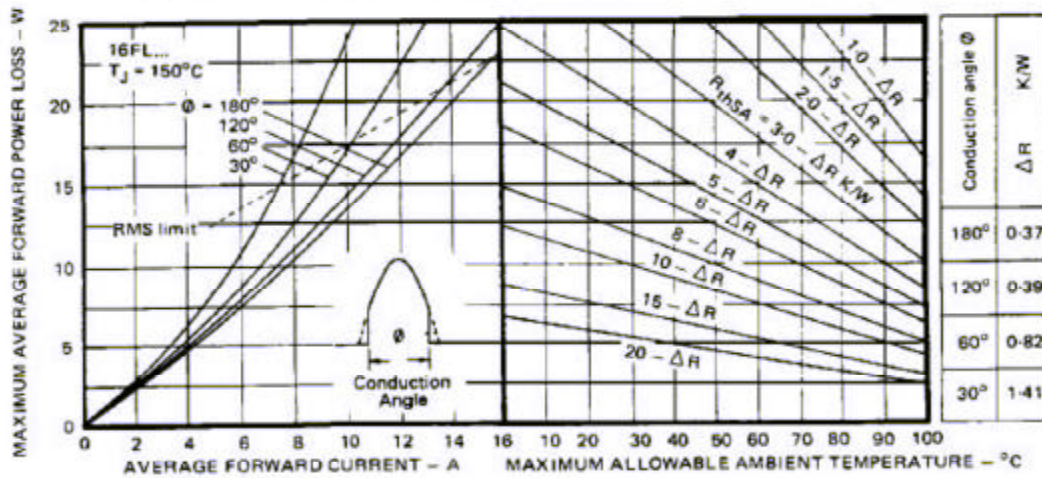


Fig. 9 - Current Rating Nomogram (Sinusoidal Waveforms), 16FL Series

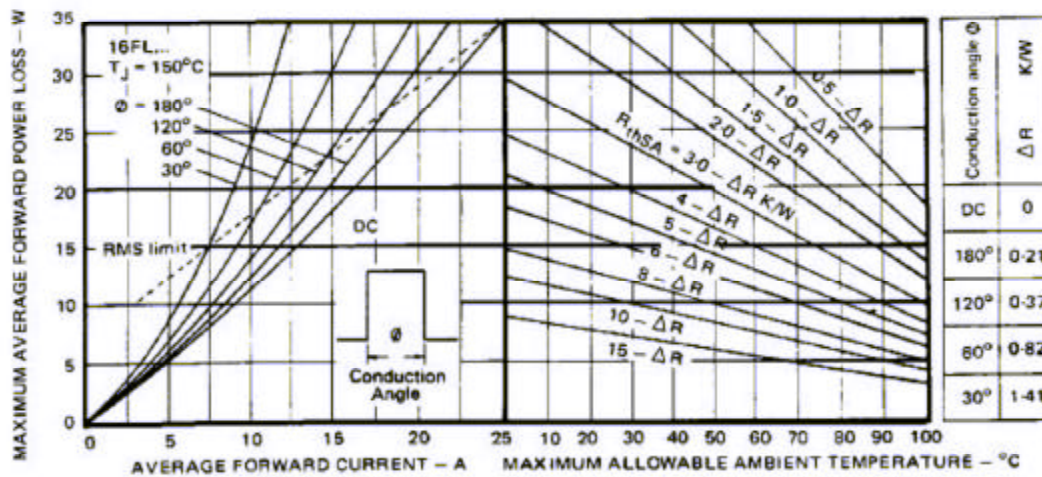


Fig. 10 - Current Rating Nomogram (Rectangular Waveforms), 16FL Series

1N3879, 1N3889, 6FL, 12FL, 16FL Series

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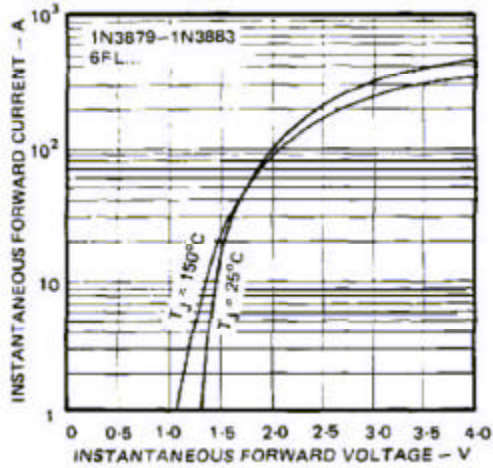


Fig. 11 - Maximum Forward Voltage Vs. Forward Current, 1N3879 and 6FL Series

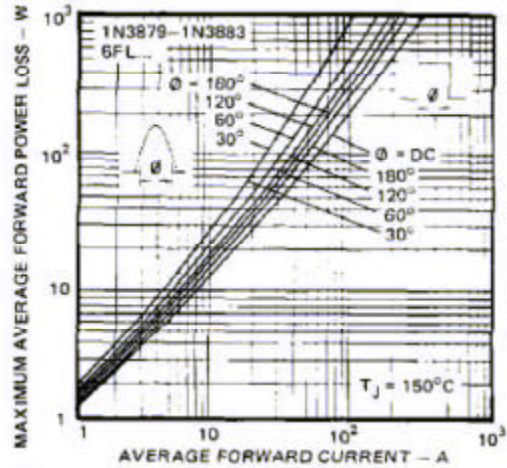


Fig. 12 - Maximum High Level Forward Power Loss Vs. Average Forward Current, 1N3879 and 6FL Series

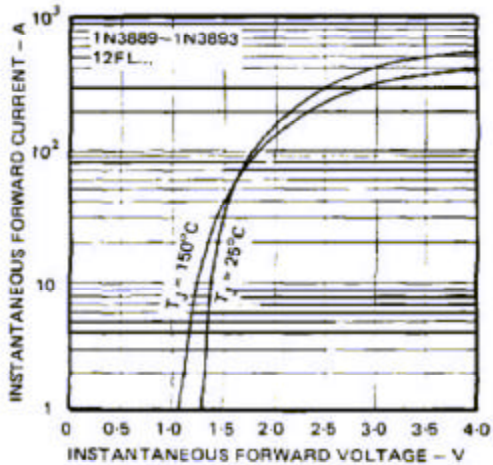


Fig. 13 - Maximum Forward Voltage Vs. Forward Current, 1N3889 and 12FL Series

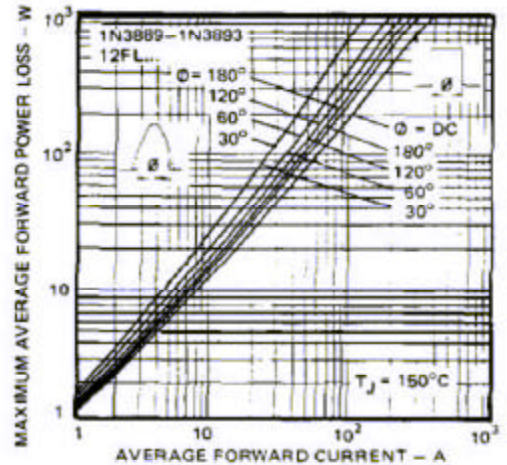


Fig. 14 - Maximum High Level Forward Power Loss Vs. Average Forward Current, 1N3889 and 12FL Series

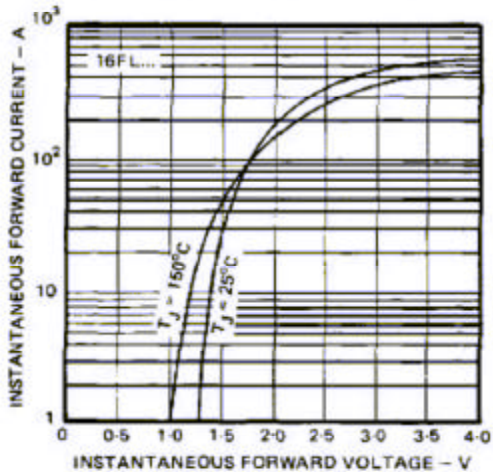


Fig. 15 - Maximum Forward Voltage Vs. Forward Current, 16FL Series

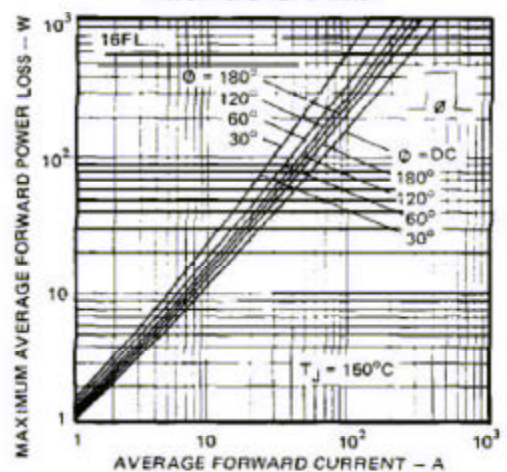


Fig. 16 - Maximum High Level Forward Power Loss Vs. Average Forward Current, 16FL Series



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1N3879, 1N3889, 6FL, 12FL, 16FL Series

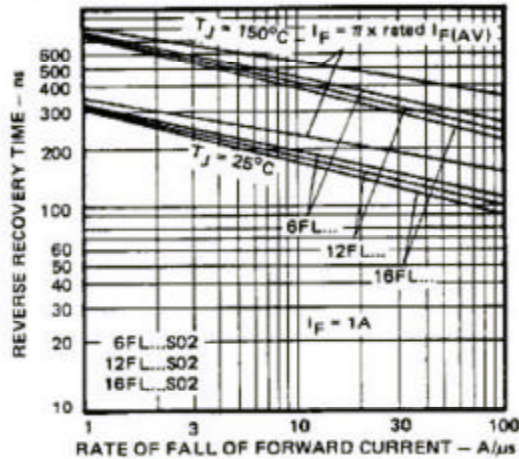


Fig. 17A — Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, All Series __S02

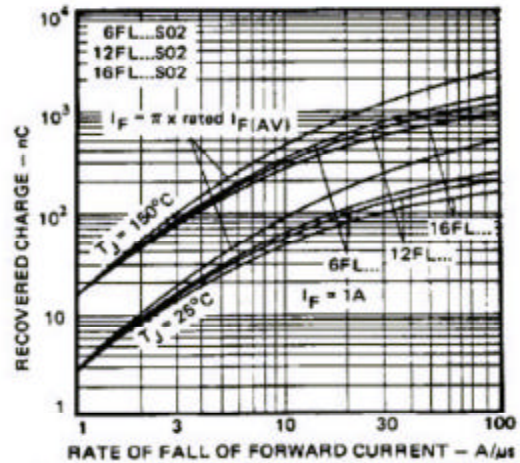


Fig. 17B — Typical Recovered Charge Vs. Rate of Fall of Forward Current, All Series __S02

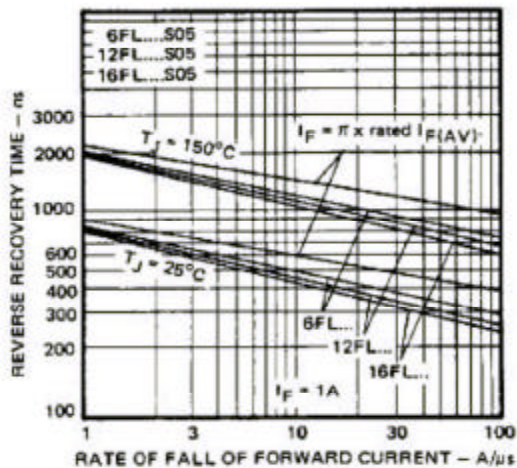


Fig. 18A — Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, All Series __S05

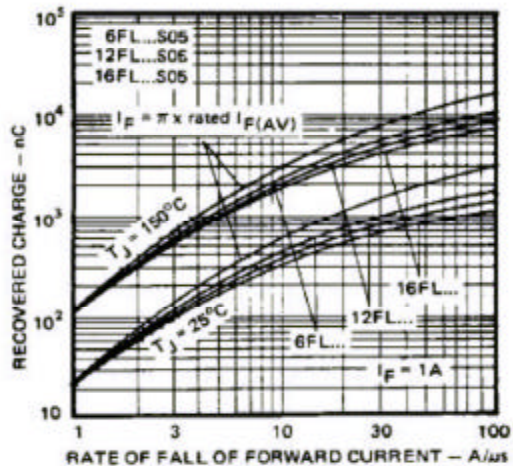


Fig. 18B — Typical Recovered Charge Vs. Rate of Fall of Forward Current, All Series __S05

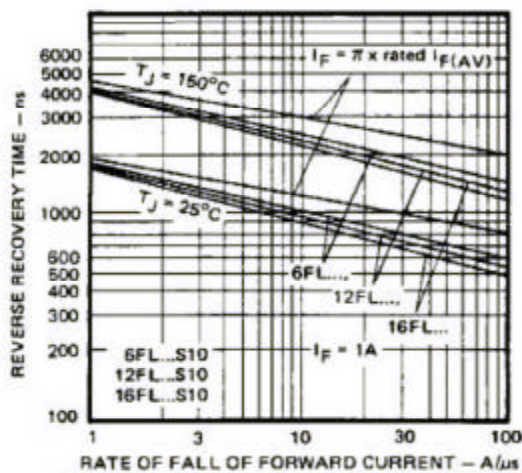


Fig. 19A — Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, All Series __S10

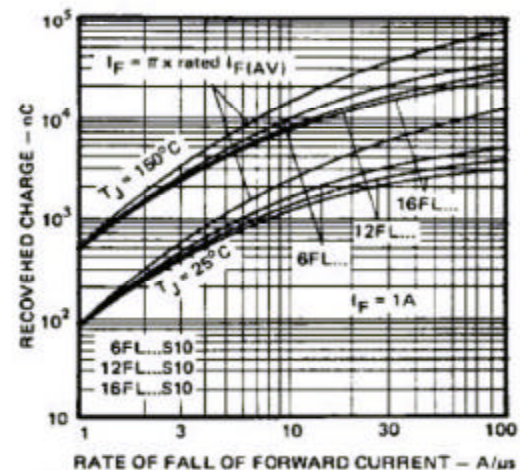


Fig. 19B — Typical Recovered Charge Vs. Rate of Fall of Forward Current, All Series __S10

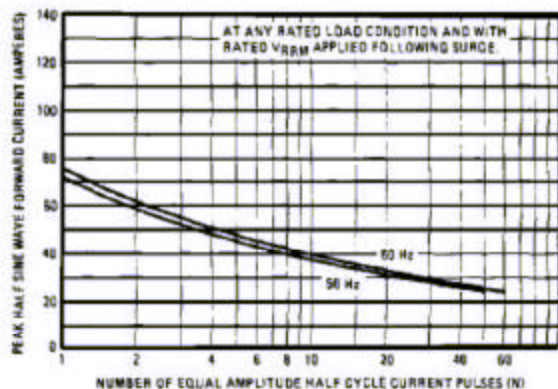


Fig. 20 - Maximum Non-Repetitive Surge Current Vs. Number of Current Pulses, 1N3879 Series

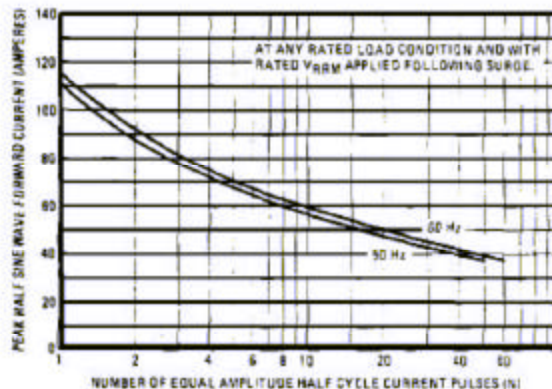


Fig. 21 - Maximum Non-Repetitive Surge Current Vs. Number of Current Pulses, 6FL Series

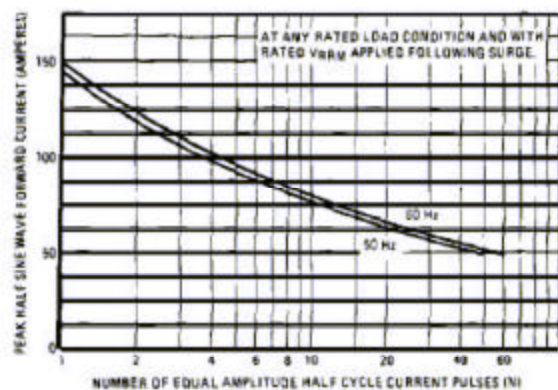


Fig. 22 - Maximum Non-Repetitive Surge Current Vs. Number of Current Pulses, 1N3889 and 12FL Series

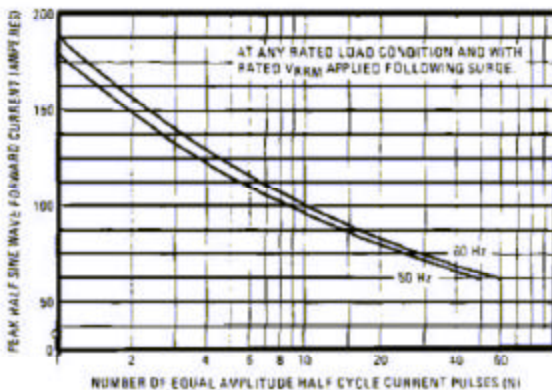


Fig. 23 - Maximum Non-Repetitive Surge Current Vs. Number of Current Pulses, 16FL Series

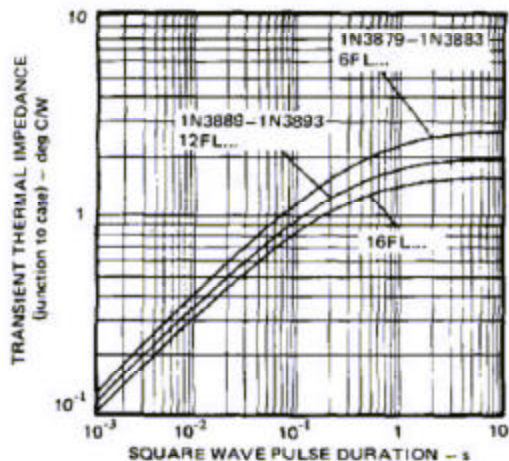


Fig. 24 - Maximum Transient Thermal Impedance, Junction-to-Case Vs. Pulse Duration, All Series.